MOSFET – Power, Single N-Channel, TDFNW8 DUAL COOL[®] 150 V, 4.45 mΩ, 174 A

NTMTSC4D3N15MC

Features

- Small Footprint (8x8 mm) for Compact Design
- Low R_{DS(on)} to Minimize Conduction Losses
- Low Q_G and Capacitance to Minimize Driver Losses
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

Typical Applications

- Power Tools, Battery Operated Vacuums
- UAV/Drones, Material Handling
- BMS/Storage, Home Automation

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Symbol	Parameter			Value	Unit
V_{DSS}	Drain-to-Source Voltage			150	V
V_{GS}	Gate-to-Source Voltage		±20	V	
I _D	Continuous Drain Current $R_{\theta JC}$ (Note 2)	Steady State	T _C = 25°C	174	Α
P _D	Power Dissipation $R_{\theta JC}$ (Note 2)			293	W
I _D	Continuous Drain Current $R_{\theta JA}$ (Notes 1, 2)	Steady State	T _A = 25°C	22	Α
P _D	Power Dissipation $R_{\theta JA}$ (Notes 1, 2)			5	W
I _{DM}	Pulsed Drain Current	$T_A = 25^{\circ}C, t_p = 10 \mu s$		900	Α
T _J , T _{stg}	Operating Junction and Storage Temperature Range		-55 to +175	°C	
I _S	Source Current (Body Diode)			244	Α
E _{AS}	Single Pulse Drain-to-Source Avalanche Energy (I _L = 48.5 A _{pk} , L = 0.3 mH)			354	mJ
TL	Lead Temperature Soldering Reflow for Soldering Purposes (1/8" from case for 10 s)			260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

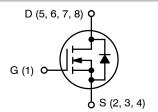
- 1. Surface–mounted on FR4 board using 1 in² pad size, 1 oz Cu pad.
- 2. The entire application environment impacts the thermal resistance values shown, they are not constants and are only valid for the particular conditions noted



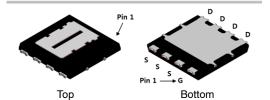
ON Semiconductor®

www.onsemi.com

V _{(BR)DSS}	R _{DS(ON)} MAX	I _D MAX
150 V	4.45 mΩ @ 10 V	174 A
150 V	5 mΩ @ 8 V	1747

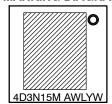


N-CHANNEL MOSFET



TDFNW8 8.3x8.4, 2P PQFN88 CASE 507AS

MARKING DIAGRAM



4D3N15M = Specific Device Code

A = Assembly Location
WL = Wafer Lot Code
Y = Year Code
W = Work Week Code

ORDERING INFORMATION

Device	Package	Shipping [†]
NTMTSC4D3N15MC	TDFNW8 (Pb-Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

THERMAL RESISTANCE RATINGS

Symbol	Parameter	Max	Unit
$R_{ hetaJC}$	Junction-to-Case - Steady State (Note 2)	0.5	°C/W
$R_{ hetaJA}$	Junction-to-Ambient - Steady State (Note 2)	30	

Unit	
V	
mV/°C	
μΑ	
μΑ	
nA	
V	
mV/°C	
mΩ	
S	
Ω	
pF	
	nC
nC	
ns	
V	
ns	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

3. Switching characteristics are independent of operating junction temperatures

TYPICAL CHARACTERISTICS

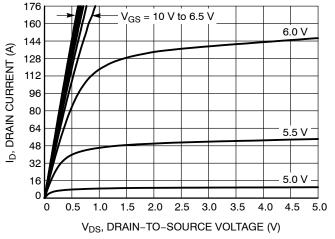


Figure 1. On-Region Characteristics

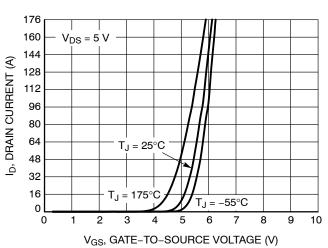


Figure 2. Transfer Characteristics

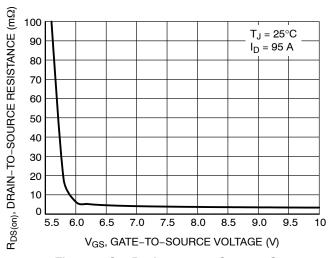


Figure 3. On-Resistance vs. Gate-to-Source Voltage

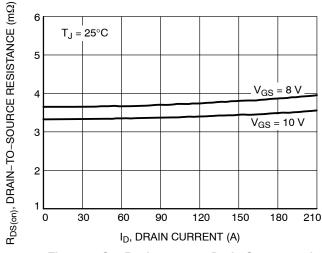


Figure 4. On-Resistance vs. Drain Current and Gate Voltage

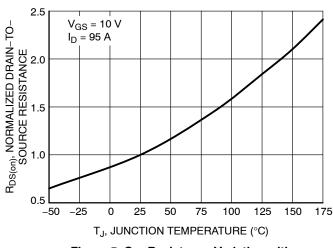


Figure 5. On–Resistance Variation with Temperature

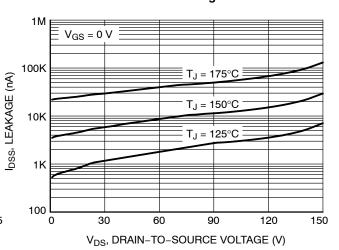
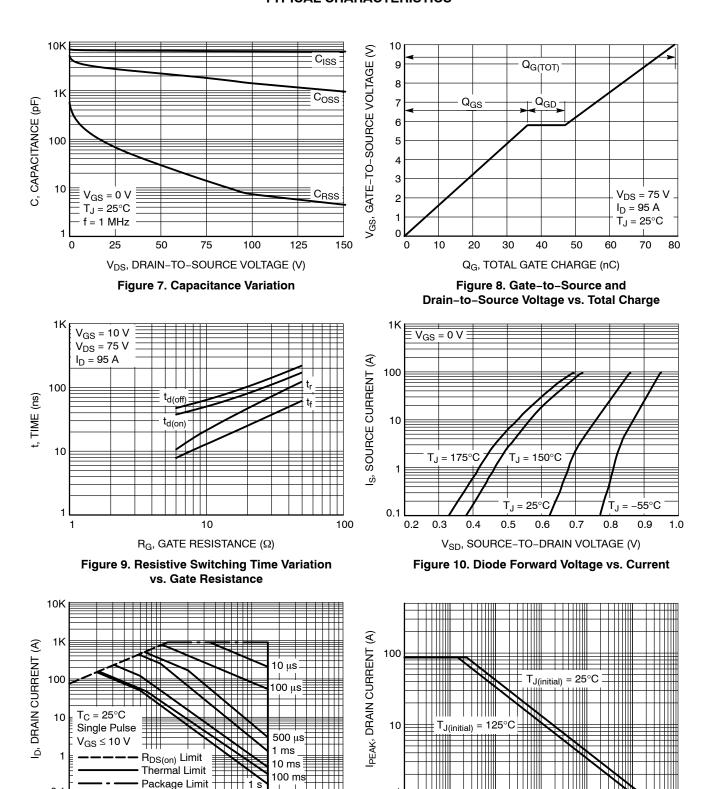


Figure 6. Drain-to-Source Leakage Current vs. Voltage

TYPICAL CHARACTERISTICS



V_{DS}, DRAIN-TO-SOURCE VOLTAGE (V) Figure 11. Safe Operating Area

100

10

0.1

TIME IN AVALANCHE (sec)

Figure 12. I_{PEAK} vs. Time in Avalanche

0.001

0.01

0.0001

0.000001 0.00001

TYPICAL CHARACTERISTICS

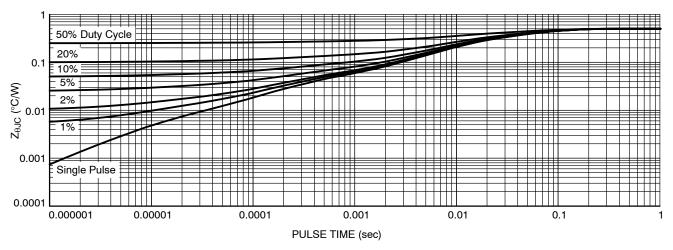
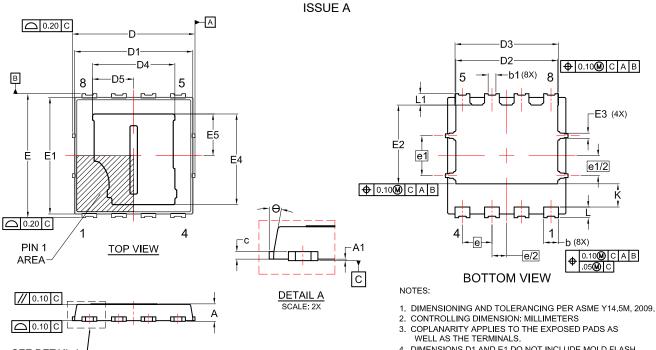


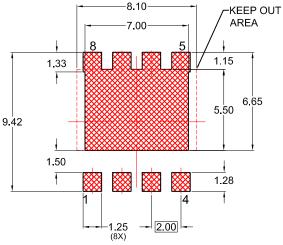
Figure 13. Thermal Characteristics

PACKAGE DIMENSIONS

TDFNW8 8.3x8.4, 2P CASE 507AS



SEE DETAIL A FRONT VIEW



RECOMMENDED LAND PATTERN

- 4. DIMENSIONS D1 AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

 5. SEATING PLANE IS DEFINED BY THE TERMINALS.

 "A1" IS DEFINED AS THE DISTANCE FROM THE SEATING PLANE TO THE LOWEST POINT ON THE PACKAGE BODY.

DIM	MILLIMETERS			
"	MIN.	NOM.	MAX.	
Α	0.82	0.92	1.02	
A1	0.00		0.05	
b	0.90	1.00	1.10	
b1	0.43	0.53	0.63	
С	0.23	0.28	0.33	
D	8.20	8.30	8.40	
D1	7.90	8.00	8.10	
D2	6.80	6.90	7.00	
D3	6.90	7.00	7.10	
D4	5.47	5.57	5.67	
D5	2.69	2.79	2.89	
Е	8.30	8.40	8.50	
E1	7.80	7.90	8.00	
E2	5.24	5.34	5.44	
E3	0.25	0.35	0.45	
E4	6.03	6.13	6.23	
E5	2.72	2.82	2.92	
е	2.00 BSC			
e/2	1.00 BSC			
e1	2.70 BSC			
e1/2	1.35 BSC			
K	1.50	1.57	1.70	
L	0.64	0.74	0.84	
L1	0.67	0.77	0.87	
θ	0°		12°	

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